

K-No.: 26669	<b>25A Current Sensor</b> For the electronic measurement of currents: DC, AC, pulsed, mixed with a galvanic Isolation between the primary circuit (high power) and the secondary circuit (electronic circuit)		Date: 12.09.2017
Customer: Standard type	Customers Part no:		Page 1 of 3

Description	Characteristics	Applications
<ul style="list-style-type: none"> <li>Closed loop (compensation) Current Sensor with magnetic probe</li> <li>Printed circuit board mounting</li> <li>Casing and materials UL-listed</li> </ul>	<ul style="list-style-type: none"> <li>excellent accuracy</li> <li>very low offset current</li> <li>very low temperature dependency and offset current drift</li> <li>very low hysteresis of offset current</li> <li>short response time</li> <li>wide frequency bandwidth</li> <li>compact design</li> <li>reduced offset ripple</li> </ul>	Mainly used for stationary operation in industrial applications: <ul style="list-style-type: none"> <li>AC variable speed drives and servo motor drives</li> <li>static converters for DC motor drives</li> <li>Battery supplied applications</li> <li>Switched Mode Power Supplies (SMPS)</li> <li>Power supplies for welding applications</li> <li>Uninterruptable Power Supplies (UPS)</li> </ul>

**Electrical data - Ratings**

I <sub>PN</sub>	Primary nominal RMS current	25	A
V <sub>OUT</sub>	Output voltage @ I <sub>P</sub>	V <sub>REF</sub> ± (0.625*I <sub>P</sub> /I <sub>PN</sub> )	V
V <sub>OUT</sub>	Output voltage @ I <sub>P</sub> =0A, θ <sub>A</sub> =25°C	V <sub>REF</sub> ± 0.00135	V
V <sub>REF</sub>	External Reference voltage range	0 ... 4	V
	Internal Reference voltage	2.5 ± 0.005	V
K <sub>N</sub>	Transformation ratio	1...4 : 2000	

**Accuracy – Dynamic performance data**

		min.	typ.	max.	Unit
I <sub>P,max</sub>	Max. measuring range	±85			A
X	Accuracy @ I <sub>PN</sub> , θ <sub>A</sub> = 25°C		0.7		%
ε <sub>L</sub>	Linearity		0.1		%
V <sub>OUT</sub> -V <sub>REF</sub>	Offset voltage @ I <sub>P</sub> = 0A, θ <sub>A</sub> = 25°C		±1.35		mV
ΔV <sub>O</sub> /V <sub>REF</sub> /ΔT	Temperature drift of V <sub>OUT</sub> @ I <sub>P</sub> =0A, V <sub>REF</sub> =2.5V, θ <sub>A</sub>	2	10		ppm/°C
t <sub>r</sub>	Response time		0.3		μs
t <sub>ra</sub>	Reaction time		0.2		μs
f <sub>BW</sub>	Frequency bandwidth	DC..200			kHz

**General data**

θ <sub>A</sub>	Ambient operation temperature	-40	85	°C
θ <sub>S</sub>	Ambient storage temperature	-40	85	°C
m	Mass	12		g
V <sub>C</sub>	Supply voltage	4.75	5	5.25
I <sub>c</sub>	Supply current at I <sub>P</sub> = 0A and RT	15		mA

<sup>1)</sup> S <sub>clear</sub>	Clearance (component without solder pad)	9.6		mm
<sup>1)</sup> S <sub>creep</sub>	Creepage (component without solder pad)	10.6		mm
<sup>1)</sup> U <sub>sys</sub>	System voltage *determines impulse voltage acc. table 7		600	V <sub>RMS</sub>
<sup>1)</sup> U <sub>AC</sub>	Working voltage *acc. table 10		1000	V <sub>RMS</sub>
<sup>1)</sup> U <sub>PD</sub>	Rated discharge voltage *acc. table 24 with U <sub>PD</sub> = U <sub>AC</sub> * √2 max. Potential Difference acc. to UL 508	1414		V <sub>PEAK</sub>
			600	V <sub>RMS</sub>

- 1) Constructed and manufactured and tested in accordance with IEC 61800-5-1:2007 (primary to secondary)  
Reinforced insulation, Insulation material group 1, Pollution degree 2, Overvoltage category III

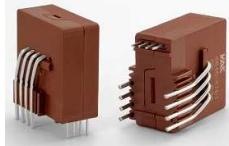
The current sensor passed the EMI susceptibility tests (vertical and horizontal, one direction) according to the standard 61000-4-3:2010 at 20V/m, 80%AM@1kHz over the frequency range of 80MHz to 1000MHz, level a) with <2% variation of the Vout during the stress.

Date	Name	Issue	Amendment
12.09.2017	SB	81	Mechanical outline changed: Tolerances grid distance +/- 0.25mm added. CN-17-291
Hrg.: R&D-PD NPI editor	Bearb.: DJ designer	MC-PM: SN check	freig.: BEF released

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### Mechanical outline (mm):

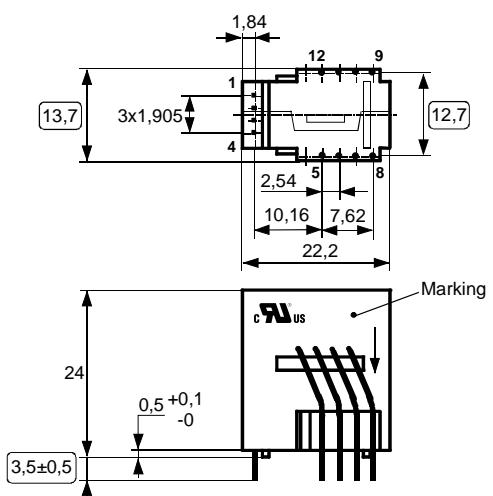
General tolerances DIN ISO 2768-C

Connections:

Pin Nr. 5-12: Ø1mm  
Pin Nr. 1-4: 0.46 x 0.46mm

Marking:  
**VAC**

UL-sign 4647-X761  
F DC



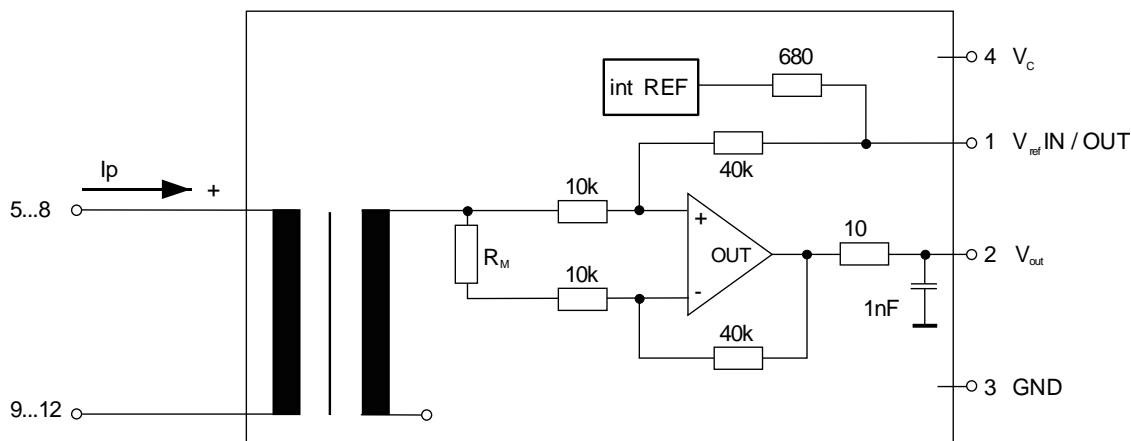
□ test dimension

Tolerances grid distance ±0,25mm

DC= Date Code  
F = Factory

Date Code Format: YWW

### Schematic diagram:



Hrg.: R&D-PD NPI  
editor

Bearb.: DJ  
designer

MC-PM: SN  
check

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<b>Electrical data:</b> (investigate by a type checking)		min.	typ.	max.	Unit
$V_{C,tot}$	maximum supply voltage (without function)			7	V
$I_C$	Supply Current with primary current		$15mA + I_P \cdot K_N + V_{OUT}/R_L$		mA
$I_{OUT,SC}$	Short circuit output current		$\pm 20$		mA
$R_P$	Resistance per primary winding @ $\vartheta_A=25^\circ C$		1		$m\Omega$
$R_S$	Secondary coil resistance @ $\vartheta_A = 85^\circ C$			67	$\Omega$
$R_{i,REF}$	Internal resistance of Reference output		680		$\Omega$
$R_{i,Vout}$	Output resistance of $V_{OUT}$		10		$\Omega$
$R_L$	External recommended resistance of $V_{OUT}$	1			$k\Omega$
$C_L$	External recommended capacitance of $V_{OUT}$		1		$nF$
$X_{Ti} / \Delta T$	Temperature drift of X @ $\vartheta_A = -40^\circ C ... 85^\circ C$			40	ppm/K
$\Delta V_O = \Delta(V_{OUT} - V_{REF})$	Sum of any offset drift including:	2	6		mV
$V_{Ot}$	Long term drift of $V_O$	1			mV
$V_{OT}$	Temperature drift of $V_O$ @ $\vartheta_A = -40^\circ C ... 85^\circ C$	1			mV
$V_{OH}$	Hysteresis of $V_{OUT}$ @ $I_P = 0A$ (caused by $I_P = 10 \times I_{PN}$ )		2		mV
$\Delta V_O / \Delta V_c$	Supply voltage rejection ratio		1		$mV/V$
$V_{OSS}$	Offsetripple (with 1 MHz-Filter, first order)			25	$mV_{PP}$
$V_{OSS}$	Offsetripple (with 100 kHz-Filter, first order)	4	6		$mV_{PP}$
$V_{OSS}$	Offsetripple (with 20 kHz-Filter, first order)	2	4		$mV_{PP}$
$C_k$	Maximum possible coupling capacity (primary - secondary)		10		pF
	Mechanical stress according to M3209/3 Settings: 10-2000Hz, 1min/oct., 2 hours			30	g

**Routine Tests:** (Measurement after temperature balance of the samples at room temperature, SC=significant characteristic)

$V_{OUT}$ (SC)	(100%) M3011/6:	Output voltage	$625 \pm 0.7\%$	mV
$V_O$	(100%) M3226:	Offset voltage	$\pm 1.35$	mV
$U_d$	(100%) M3014:	Test voltage, 1s	1.8	$kV_{RMS}$
$U_{PDE}$	(AQL 1/S4)		1.5	
$U_{PDE} * 1.875$	M3024:	Partial discharge voltage (extinction)	1.875	$kV_{RMS}$

**Type testing:** (Precondition acc. to M3236)

$\hat{U}_W$	M3064	HV transient test 1,2 $\mu$ s / 50 $\mu$ s-Waveform	8	kV
$U_d$	M3014	Test voltage (5s)	3.6	$kV_{RMS}$
$U_{PDE}$			1.5	
$U_{PDE} * 1.875$	M3024	Partial discharge voltage (extinction)	1.875	$kV_{RMS}$

### Other instructions:

- Current direction: A positive output voltage vs.  $V_{REF}$  appears at point  $V_{OUT}$ , if primary current flows in direction of the arrow.
- Constructed, manufactured and tested in accordance with IEC 61800-5-1:2007.
- Temperature of the primary conductor should not exceed 105°C.
- Housing and bobbin material UL-listed: Flammability class 94V-0.

Hrg.: R&D-PD NPI editor	Bearb.: DJ designer		MC-PM: SN check			freig.: BEF released
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